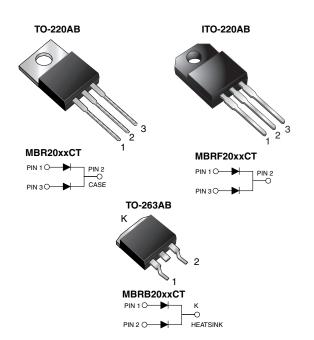


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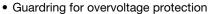
Dual Common Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V_{RRM}	35 V to 60 V				
I _{FSM}	150 A				
V _F	0.57 V, 0.70 V				
T _J max.	150 °C				
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Dual common cathode				

FEATURES

Power pack



- · Low power loss, high efficiency
- Low forward voltage drop
- High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3_A
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR2035CT	MBR2045CT	MBR2060CT	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	60	
Working peak reverse voltage	V_{RWM}	35	45	60	V
Maximum DC blocking voltage	V_{DC}	35	45	60	
Maximum average forward rectified current total device		20			
at T _C = 135 °C per diode	I _{F(AV)}	10			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150		Α	
Peak repetitive reverse surge current per diode at $t_p = 2.0 \mu s$, 1 kHz	I _{RRM}	1.0 0.5		0.5	
Voltage rate of change (rated V _R)	dV/dt	10 000			V/µs
Operating junction temperature range	TJ	-65 to +150			°C
Storage temperature range	T _{STG}	-65 to +175			
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V



MBR20xxCT, MBRF20xxCT, MBRB20xxCT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	TEST CO	ONDITIONS	MBR2035CT	MBR2045CT	MBR2060CT	UNIT
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 10 A	T _C = 25 °C	0.65		0.80	V
		I _F = 10 A	T _C = 125 °C	0.57		0.70	
		I _F = 20 A	T _C = 25 °C	0.84		0.95	
		I _F = 20 A	T _C = 125 °C	0.72		0.85	
Maximum reverse current at DC blocking voltage per diode	I _R ⁽²⁾	Rated V _R	T _C = 25 °C	0.1		0.15	- mA
			T _C = 125 °C	15		150	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical resistance from junction to case per diode	$R_{\theta JC}$	2.0	5.0	2.0	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR2045CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2045CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB2045CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB2045CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR2045CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2045CTHE3/45 1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB2045CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB2045CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		
TO-263AB	MBRB2045CTHE3_A/P (1)	1.35	Р	50/tube	Tube		
TO-263AB	MBRB2045CTHE3_A/I (1)	1.35	I	800/reel	Tape and reel		

Note

⁽¹⁾ AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

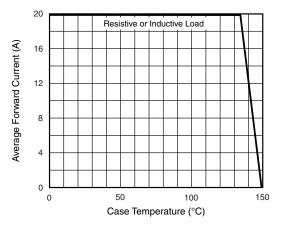


Fig. 1 - Forward Derating Curve (Total)

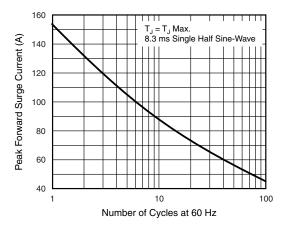


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

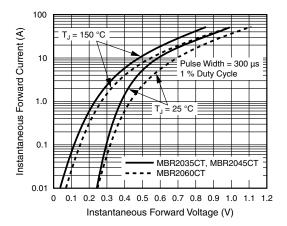


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

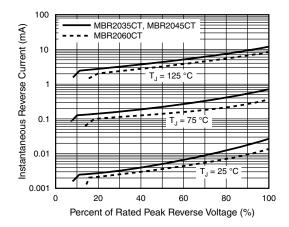


Fig. 4 - Typical Reverse Characteristics Per Diode

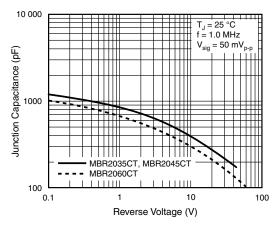


Fig. 5 - Typical Junction Capacitance Per Diode

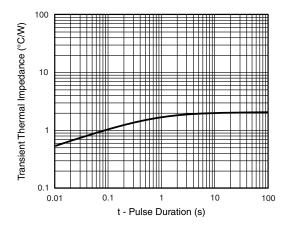


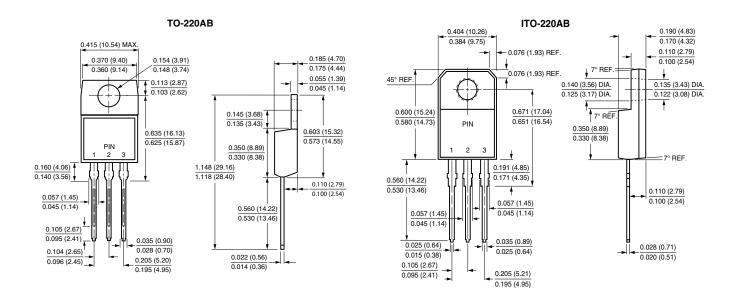
Fig. 6 - Typical Transient Thermal Impedance Per Diode

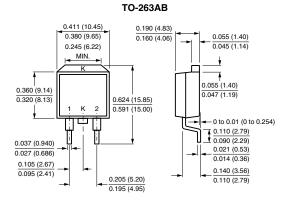




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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





0.42 (10.66) MIN. 0.670 (17.02) 0.591 (15.00) 0.08 (2.032) MIN. 0.105 (2.67) 0.095 (2.41)

Mounting Pad Layout





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